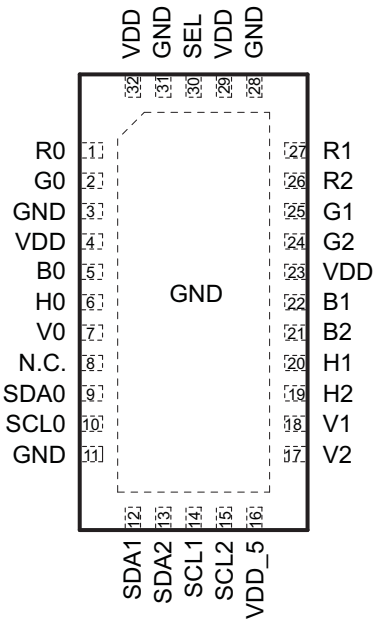
7-CHANNEL, 1:2 VIDEO SWITCH WITH INTEGRATED LEVEL SHIFTERS

Check for Samples: TS3V713EL

FEATURES

- **Supports 7-channel VGA Signals (R, G, B, H_{SYNC}, V_{SYNC}, DDC CLK, and DDC DAT)**
- **Operating Voltage**
  - **V_{DD} = 3.3 V ±10%**
  - **V_{DD_5} = 5 V ±10%**
- **High Bandwidth of 1.3 GHz (–3 dB)**
- **R, G, B Switches**
  - **R_{ON} = 4 Ω (Typ.)**
  - **C_{ON} = 8 pF (Typ.)**
- **Integrated Level Shifting Buffers for H_{SYNC} and V_{SYNC} Channels**
- **Voltage Clamping NMOS Switches for SCL and SDA Channels**
- **ESD Performance (Pins 12–15, 17–22, 24–27)**
  - **±2-kV Contact Discharge (IEC61000-4-2)**
  - **8 kV Human Body Model (JESD22-A114E)**
- **ESD Performance (All Pins)**
  - **4 kV Human Body Model (JESD22-A114E)**
- **32-Pin Quad Flat Pack No-Lead (QFN) Package**

RTG PACKAGE
(TOP VIEW)



The exposed center pad must be connected to GND.

APPLICATIONS

- **Notebook Computers**
- **Docking Stations**
- **KVM Switches**

DESCRIPTION/ORDERING INFORMATION

The TS3V713EL is a high bandwidth, 7-channel video multiplexer/demultiplexer for switching between a single VGA source and one of two end points. The device is designed for ensuring video signal integrity and minimizing video signal attenuation by providing high bandwidth of 1.3 GHz.

The TS3V713EL has integrated level shifting buffers for the H_{SYNC} and V_{SYNC} signals which provide voltage level translation between 3.3V and 5V logic. The SCL and SDA lines use NMOS switches which clamp the output voltage to 1 V below V_{DD}.

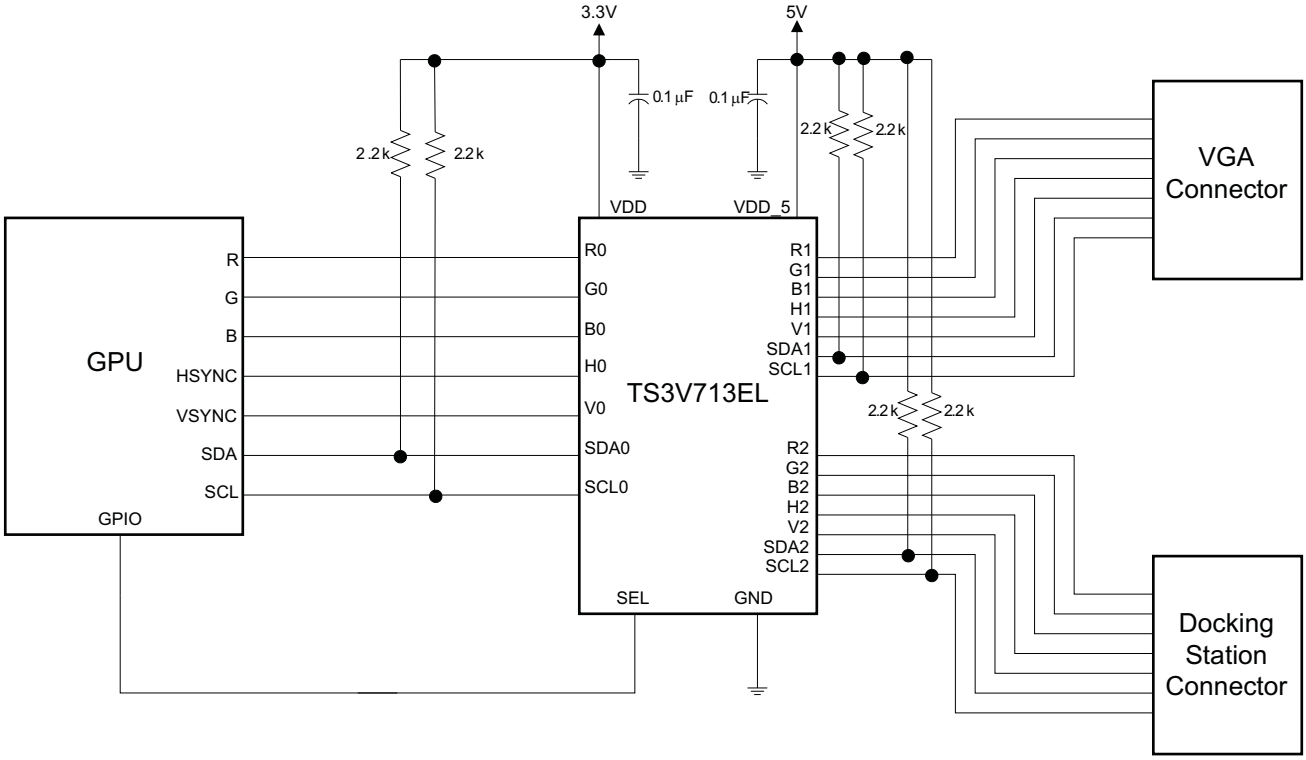
The video signals are protected against ESD with integrated diodes to V_{DD} and GND that support levels up to ±2 kV Contact Discharge (IEC61000-4-2) and 8 kV Human Body Model (JESD22-A114E).

ORDERING INFORMATION(1)

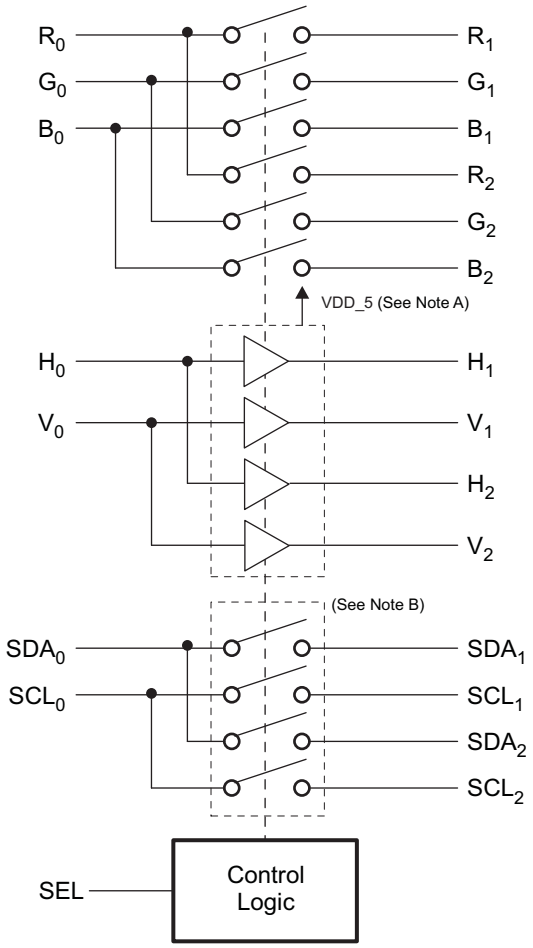
T_A	PACKAGE(2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RTG	Tape and reel	TS3V713ELRTGR	TF713EL

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

TYPICAL APPLICATION DIAGRAM



LOGIC DIAGRAM



A. Supply for H_{SYNC} and V_{SYNC} translators

B. Output clamped to V_{DD} – 1 V

FUNCTION TABLE

SEL	FUNCTION	
	R_0, G_0, B_0, H_0, V_0, SCL_0, SDA_0	**Hi-Z**
L	R_1, G_1, B_1, H_1, V_1, SCL_1, SDA_1	R_2, G_2, B_2, H_2, V_2, SCL_2, SDA_2
H	R_2, G_2, B_2, H_2, V_2, SCL_2, SDA_2	R_1, G_1, B_1, H_1, V_1, SCL_1, SDA_1

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{DD}	Supply voltage range		–0.5	4.6	V
V_{DD_5}			–0.5	6.5	
$V_{I/O}$	Analog voltage range(2)(3)	R, G, B, SCL, SDA	–0.5	V_{DD} + 0.5	V
V_{IN}	Digital input voltage range(2)(3)	SEL, H, V	–0.5	6.5	V
$I_{I/OK}$	Analog port diode current	$V_{I/O}$ < 0 V		–50	mA
I_{IK}	Digital input clamp current	V_{IN} < 0 V		–50	mA
$I_{I/O}$	ON-state switch current	R, G, B, SCL, SDA	–128	128	mA
I_{DD}	Continuous current through V_{DD} or GND		–100	100	mA
I_{GND}					
θ_{JA}	Package thermal impedance(4)	RTG package(4)		39.2	°C/W
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground, unless otherwise specified.
(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) The package thermal impedance is calculated in accordance with JESD 51-1.

RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT
V_{DD}	Supply voltage		3	3.6	V
V_{DD_5}	Supply voltage for H and V channels		4.5	5.5	V
V_{IN}	Digital control input voltage	SEL, H, V	0	5.5	V
V_{IH}	High-level control input voltage	SEL, H, V	2		V
V_{IL}	Low-level control input voltage	SEL, H, V		0.8	V
I_{OH}	High-level output current	H, V		–8	mA
I_{OL}	Low-level output current	H, V		8	mA
T_A	Operating free-air temperature		–40	85	°C

(1) All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS(1)

over recommended operating free-air temperature range, V_{DD} = 3.3 V ±0.3 V, V_{DD_5} = 5 V ±0.5 V (unless otherwise noted)

PARAMETER			TEST CONDITIONS				MIN	TYP(2)	MAX	UNIT
V_{IK}	Digital input clamp voltage	SEL, H, V	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	I_{IN} = –18 mA				–0.8	–1.2	V
r_{ON}	ON-state resistance	R, G, B	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	0 V ≤ $V_{I/O}$ ≤ V_{DD},	$I_{I/O}$ = –40 mA			3	6	Ω
		SCL, SDA						4	8	
$r_{ON(flat)}$	ON-state resistance flatness(3)	R, G, B	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	$V_{I/O}$ = 1.5 V and V_{DD},	$I_{I/O}$ = –40 mA			0.2	1	Ω
Δr_{ON}	ON-state resistance match between channels(4)	R, G, B	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	0 V ≤ $V_{I/O}$ ≤ V_{DD},	$I_{I/O}$ = –40 mA			0.2	1	Ω
I_{IH}	Digital input high leakage current	SEL, H, V	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	V_{IN} = V_{DD}					±1	µA
I_{IL}	Digital input low leakage current	SEL, H, V	V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	V_{IN} = GND					±1	µA
I_{OFF}	Leakage under power off conditions	All outputs	V_{DD} = 0 V, V_{DD_5} = 0 V,	$V_{I/O}$ = 0 to 3.6 V,	V_{IN} = 0 to 5.5 V				±1	µA
C_{IN}	Digital input capacitance	SEL, H, V	f = 10 MHz	V_{IN} = 0,				4		pF
C_{OFF}	Switch OFF capacitance	R, G, B	f = 10 MHz	$V_{I/O}$ = 0 V,	Output open,	Switch OFF		2.5		pF
		SCL, SDA						2.3		
C_{ON}	Switch ON capacitance	R, G, B	f = 10 MHz	$V_{I/O}$ = 0 V,	Output open,	Switch ON		8		pF
		SCL, SDA						8.2		
V_{OH}	High-level output voltage	H, V	V_{IN} = V_{IH},	I_{OH} = –8 mA			3.8			V
V_{OL}	Low-level output voltage	H, V	V_{IN} = V_{IH},	I_{OL} = 8 mA					0.5	V
V_{HYST}	Voltage hysteresis	H, V						200	300	mV
I_{DD}	V_{DD} supply current		V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	V_{IN} = V_{DD} or GND,	$I_{I/O}$ = 0 mA,			200	500	µA
I_{DD_5}	V_{DD_5} supply current		V_{DD} = 3.6 V, V_{DD_5} = 5.5 V,	V_{IN} = V_{DD} or GND,	$I_{I/O}$ = 0 mA,				50	µA

(1) V_I, V_O, I_I, and I_O refer to I/O pins. V_{IN} refers to the control inputs.
(2) All typical values are at V_{DD} = 3.3V, V_{DD_5} = 5V (unless otherwise noted), T_A = 25°C.
(3) $r_{ON(flat)}$ is the difference of r_{ON} in a given channel at specified voltages.
(4) Δr_{ON} is the difference of r_{ON} from center port to any other ports.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 3.3 V ±0.3 V, V_{DD_5} = 5 V ±0.5 V (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP	MAX	UNIT
t_{pd} (1)	R_0,G_0, B_0	R_1, G_1, B_1 or R_2, G_2, B_2		0.25		ns
	SCL_0, SDA_0	SCL_1, SDA_1 or SCL_2, SDA_2		0.25		
	H0,V0	H1, V1 or H2, V2		3	7	
t_{PHZ}, t_{PLZ} (2)	SEL	R_1, G_1, B_1, SCL_1, SDA_1 or R_2, G_2, B_2, SCL_2, SDA_2	0.5		11	ns
	SEL	H_1, V_1 or H_2, V_2	0.5		13	
t_{PZH}, t_{PZL} (3)	SEL	R_1, G_1, B_1, SCL_1, SDA_1 or R_2, G_2, B_2, SCL_2, SDA_2	0.5		11	ns
	SEL	H_1, V_1 or H_2, V_2	0.5		13	
$t_{sk(o)}$ (4)	R, G, B			0.05	0.1	ns
$t_{sk(p)}$ (5)	R, G, B			0.05	0.1	ns

(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
(2) Line disable time: SEL to input and output; also called "SEL to Switch Turn Off Time."
(3) Line enable time: SEL to input and output; also called "SEL to Switch Turn On Time."
(4) Output skew between center channel to any other channel.
(5) Skew between opposite transitions of the same output. $|t_{PHL} - t_{PLH}|$

DYNAMIC CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 3.3 V ±0.3 V, V_{DD_5} = 5 V ±0.5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TYP (1)	UNIT
X_{TALK}	R, G, B	R_L = 50 Ω	f = 250 MHz	–50	dB
O_{IRR}	R, G, B	R_L = 50 Ω	f = 250 MHz	–40	dB
BW	R, G, B	R_L = 50 Ω	Switch ON	1.3	GHz

(1) All typical values are at V_{DD} = 3.3 V, V_{DD_5} = 5 V (unless otherwise noted)

TYPICAL CHARACTERISTICS

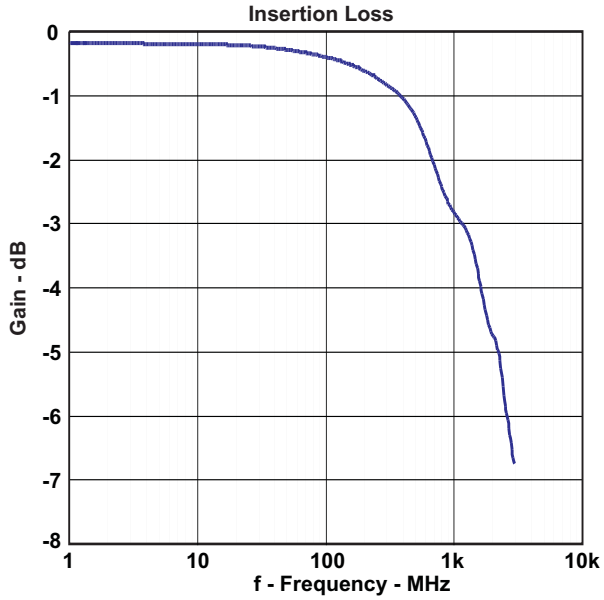


Figure 1. Gain vs Frequency

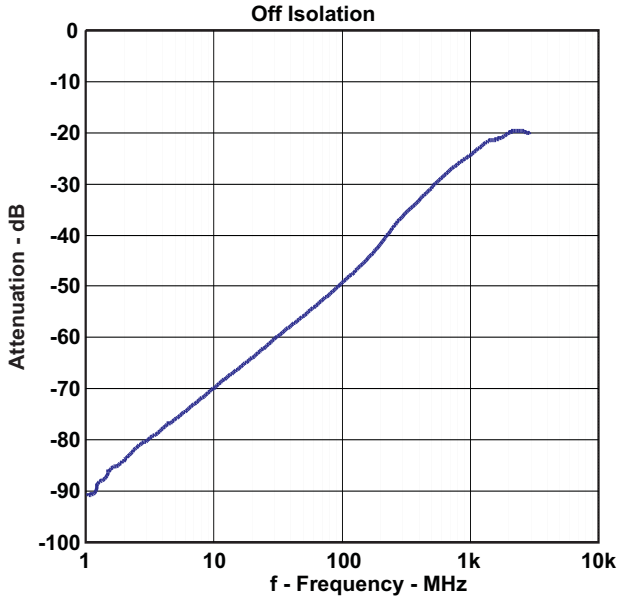


Figure 2. Off Isolation vs Frequency

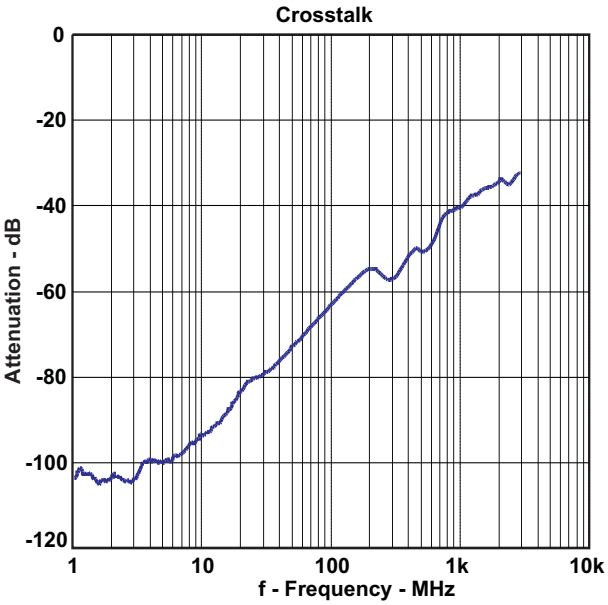


Figure 3. Crosstalk vs Frequency

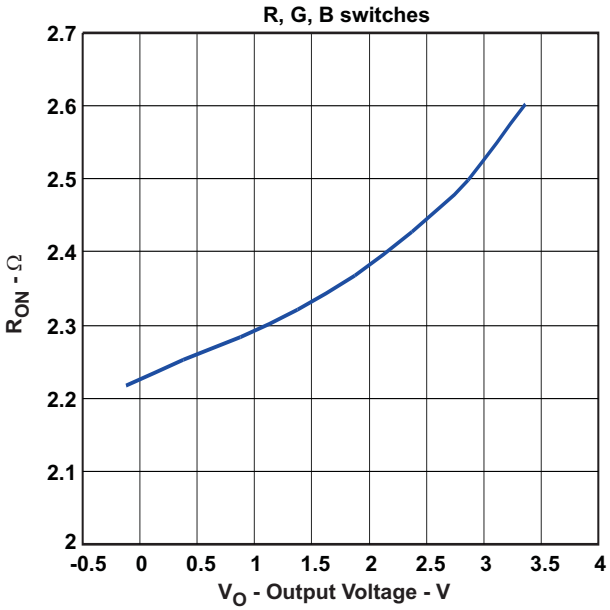


Figure 4. R_{ON} vs V_O

TYPICAL CHARACTERISTICS (continued)

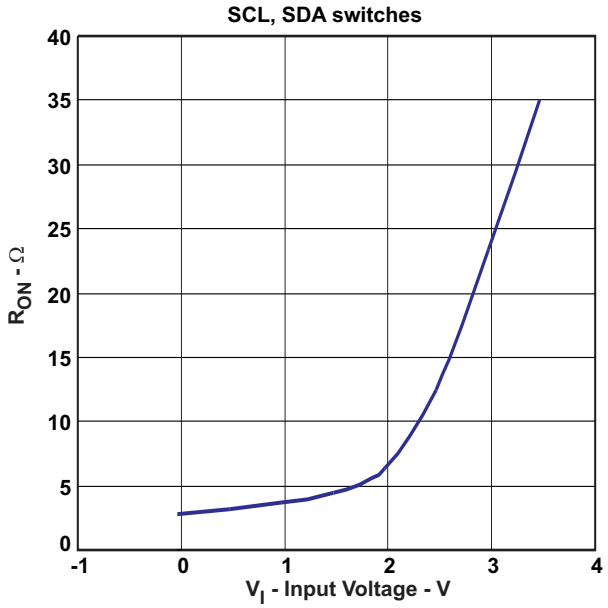


Figure 5. R_{ON} vs V_I

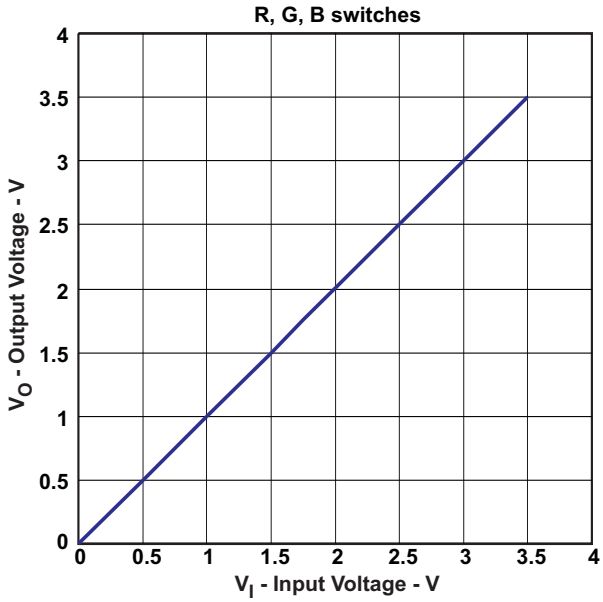


Figure 6. V_O vs V_I

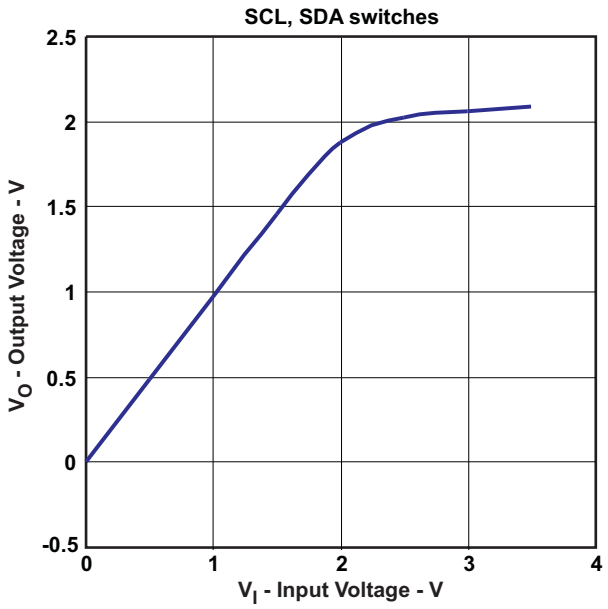


Figure 7. V_O vs V_I

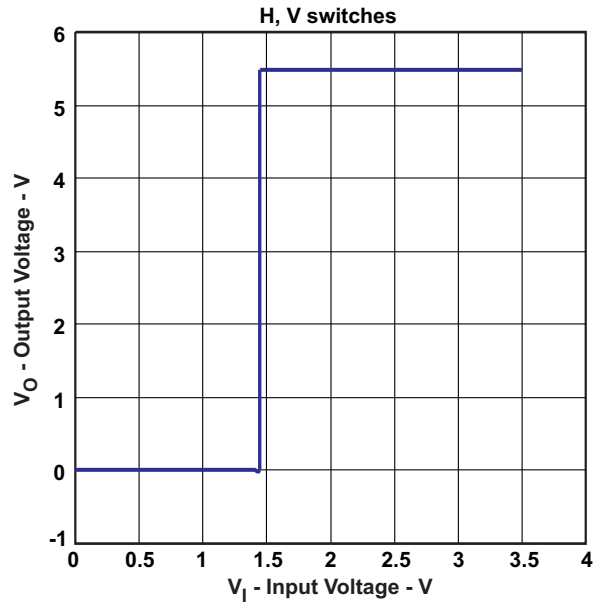
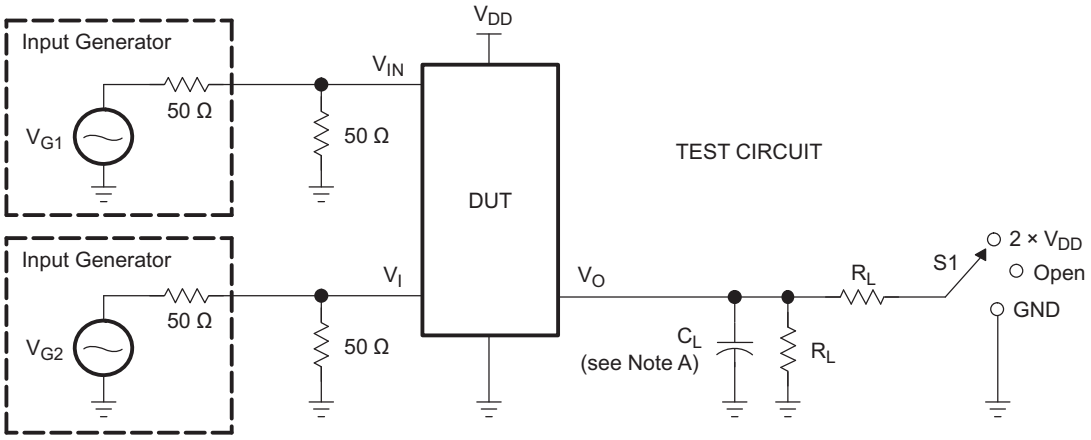


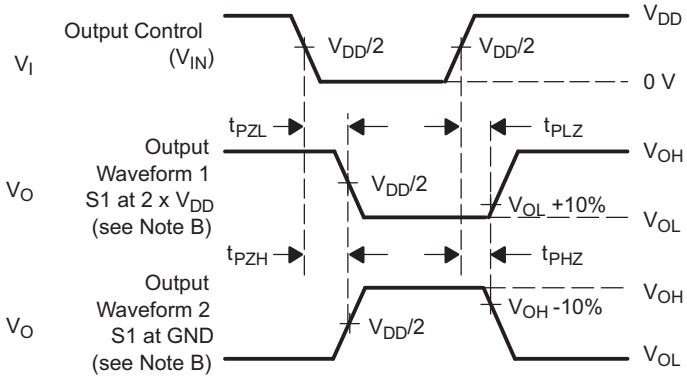
Figure 8. V_O vs V_I

PARAMETER MEASUREMENT INFORMATION
(Enable and Disable Times)



TEST	V_{DD_5}	V_{DD}	S1	R_L	V_{in}	C_L	V_Δ
t_{PLZ}/t_{PZL}	5 V± 0.5 V	3.3 V± 0.3 V	2 × V_{DD}	200 Ω or 1 kΩ*	GND	10 pF	0.3 V
t_{PHZ}/t_{PZH}	5 V± 0.5 V	3.3 V± 0.3 V	GND		V_{DD}	10 pF	0.3 V

*R_L = 200 Ω applies to all switch outputs
R_L = 1 kΩ applies to all buffer outputs

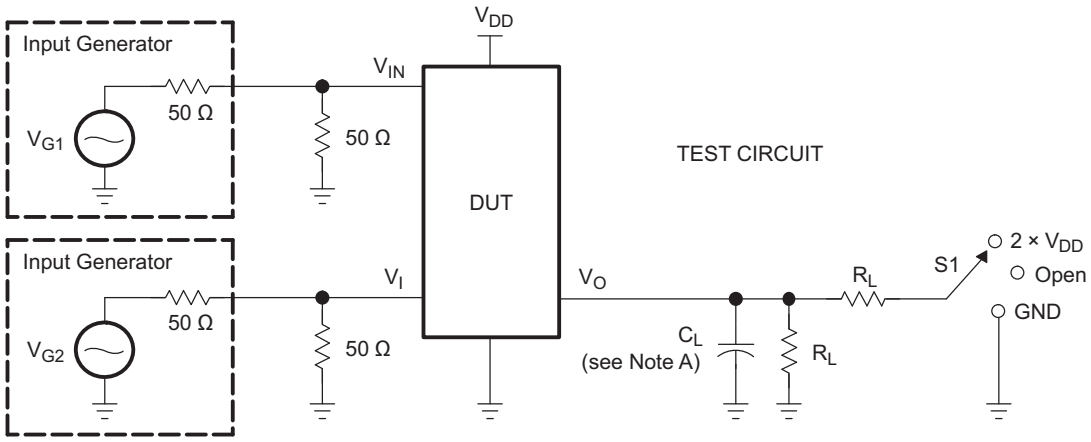


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.

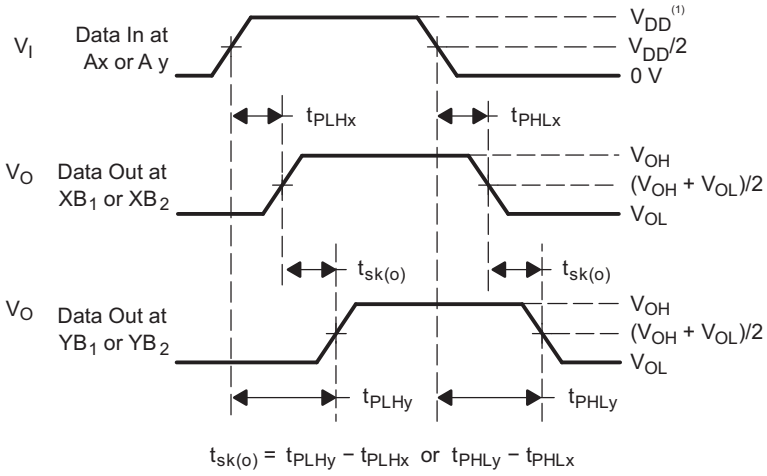
Figure 9. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION
(Propagation Delay and Skew)

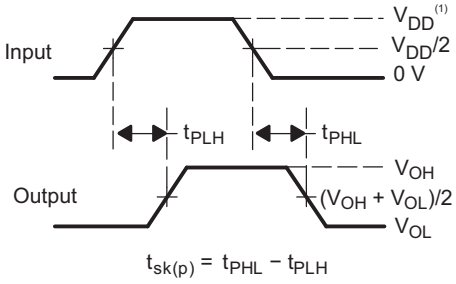


TEST	V_{DD}	V_{DD_5}	S1	R_L	V_{in}	C_L
$t_{sk(o)}$	3.3 V ± 0.3 V	5 V ± 0.5 V	Open	200 Ω* or 1 kΩ	V_{DD} or GND	10 pF
$t_{sk(p)}$	3.3 V ± 0.3 V	5 V ± 0.5 V	Open		V_{DD} or GND	10 pF

*R_L = 200 Ω applies to all switch outputs
R_L = 1 kΩ applies to all buffer outputs



VOLTAGE WAVEFORMS
OUTPUT SKEW ($t_{sk(o)}$)

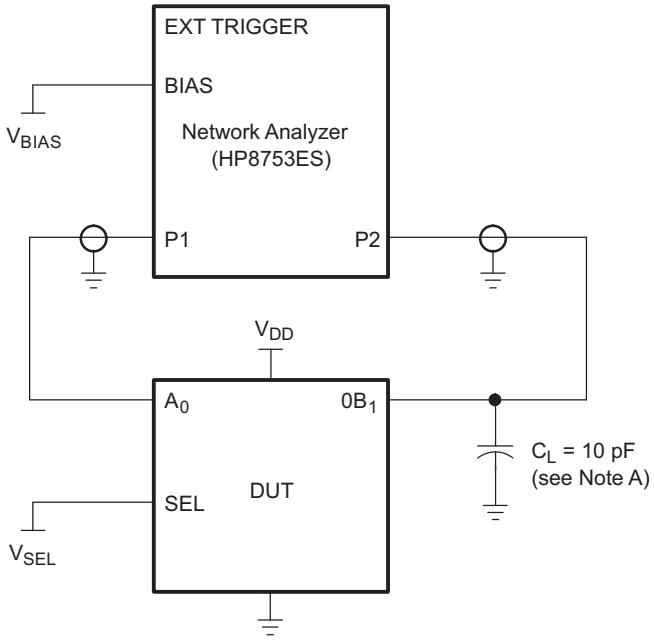


VOLTAGE WAVEFORMS
PULSE SKEW [$t_{sk(p)}$]

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time, with one transition per measurement.
(1) 2 V ± 0.2 V for SCL, SDA

Figure 10. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



A. C_L includes probe and jig capacitance.

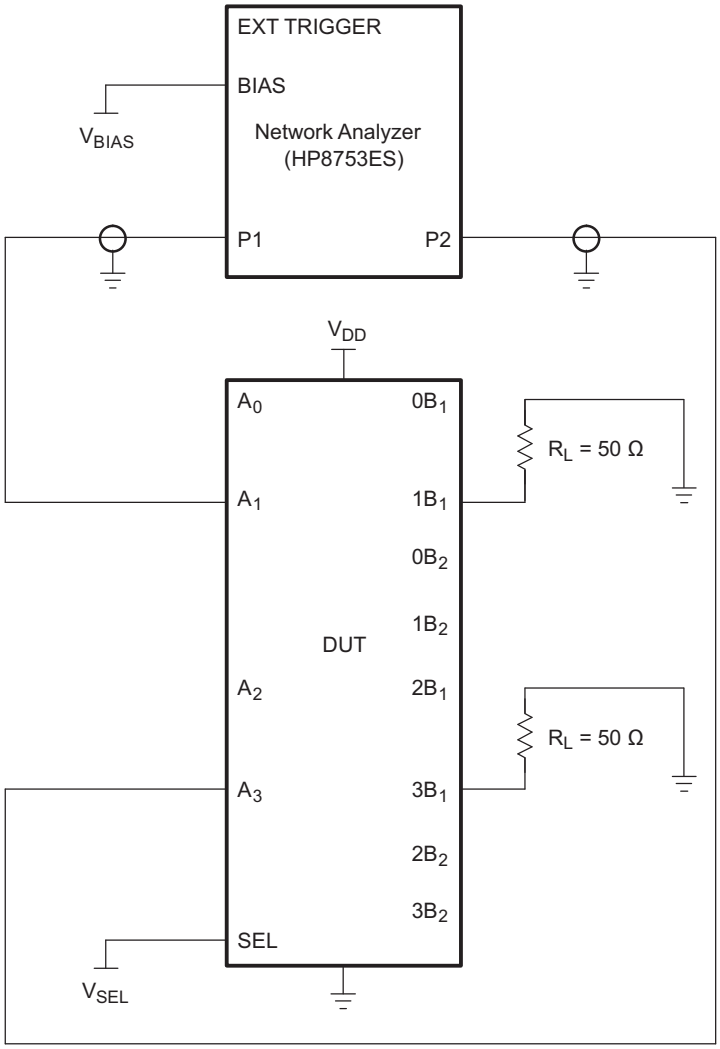
Figure 11. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when V_{SEL} = 0 and A_0 is the input, the output is measured at $0B_1$. All unused analog I/O ports are left open.

HP8753ES Setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PARAMETER MEASUREMENT INFORMATION (continued)



A. C_L includes probe and jig capacitance.

B. A 50-Ω termination resistor is needed to match the loading of the network analyzer.

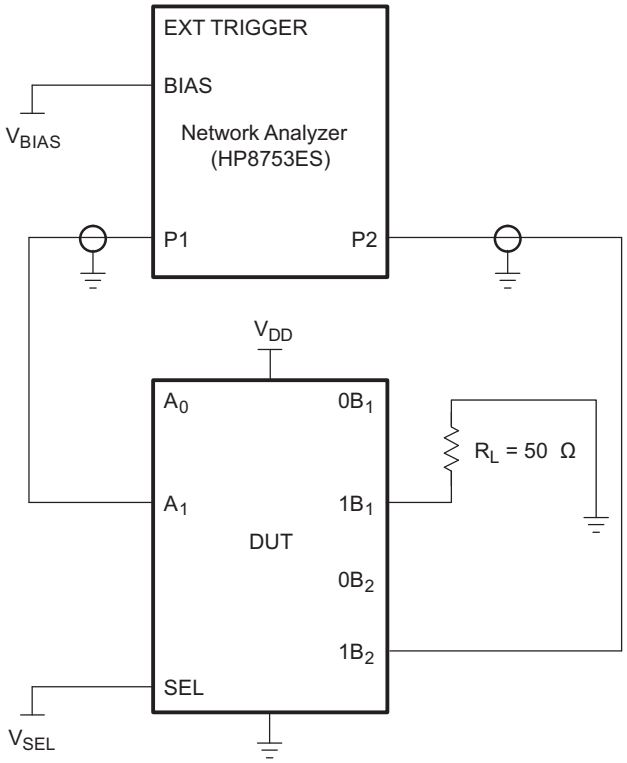
Figure 12. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when V_{SEL} = 0 and A_1 is the input, the output is measured at A_3 . All unused analog input (A) ports are connected to GND, and the output (B) ports are left open.

HP8753ES Setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PARAMETER MEASUREMENT INFORMATION (continued)



A. C_L includes probe and jig capacitance.

B. A 50-Ω termination resistor is needed to match the loading of the network analyzer.

Figure 13. Test Circuit for Off Isolation (O_{IRR})

Off isolation is measured at the output of the OFF channel. For example, when V_{SEL} = GND and A_s is the input, the output is measured at $1B_2$. All unused analog input (A) ports are connected to GND, and the output (B) ports are left open.

HP8753ES Setup

Average = 4
RBW = 3 kHz
V_{BIAS} = 0.35 V
ST = 2 s
P1 = 0 dBM

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS3V713ELRTGR	Active	Production	WQFN (RTG) | 32	3000 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	TF713EL
TS3V713ELRTGR.B	Active	Production	WQFN (RTG) | 32	3000 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	TF713EL

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

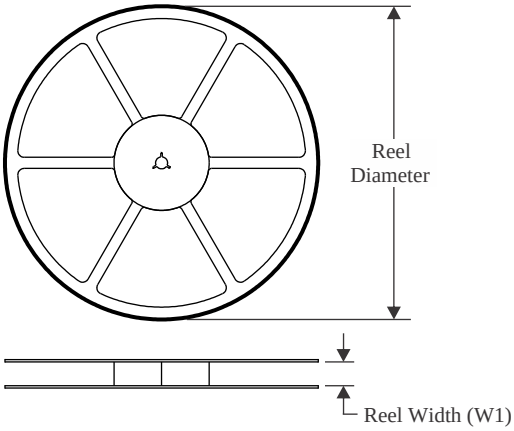
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

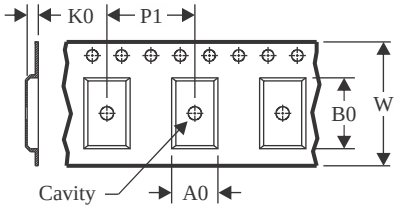
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

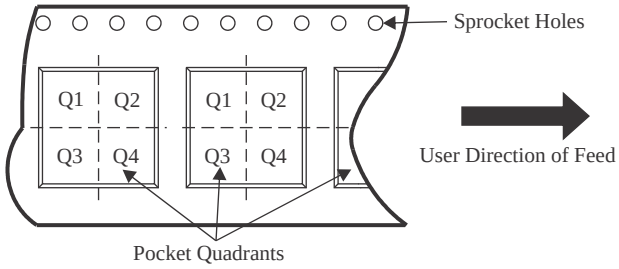


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

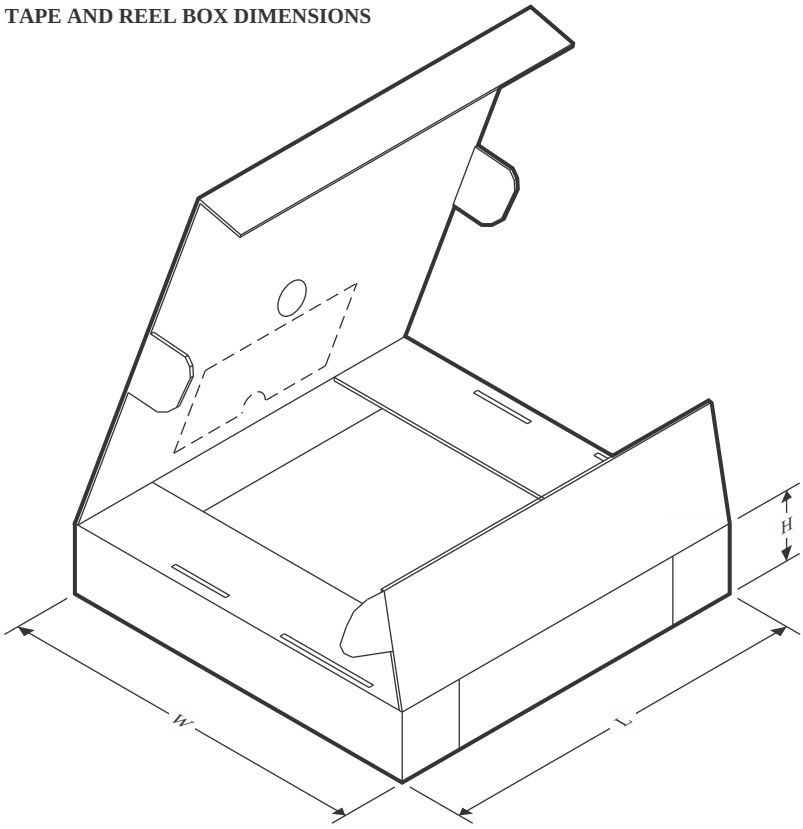
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3V713ELRTGR	WQFN	RTG	32	3000	330.0	16.4	3.3	6.3	1.0	8.0	16.0	Q1

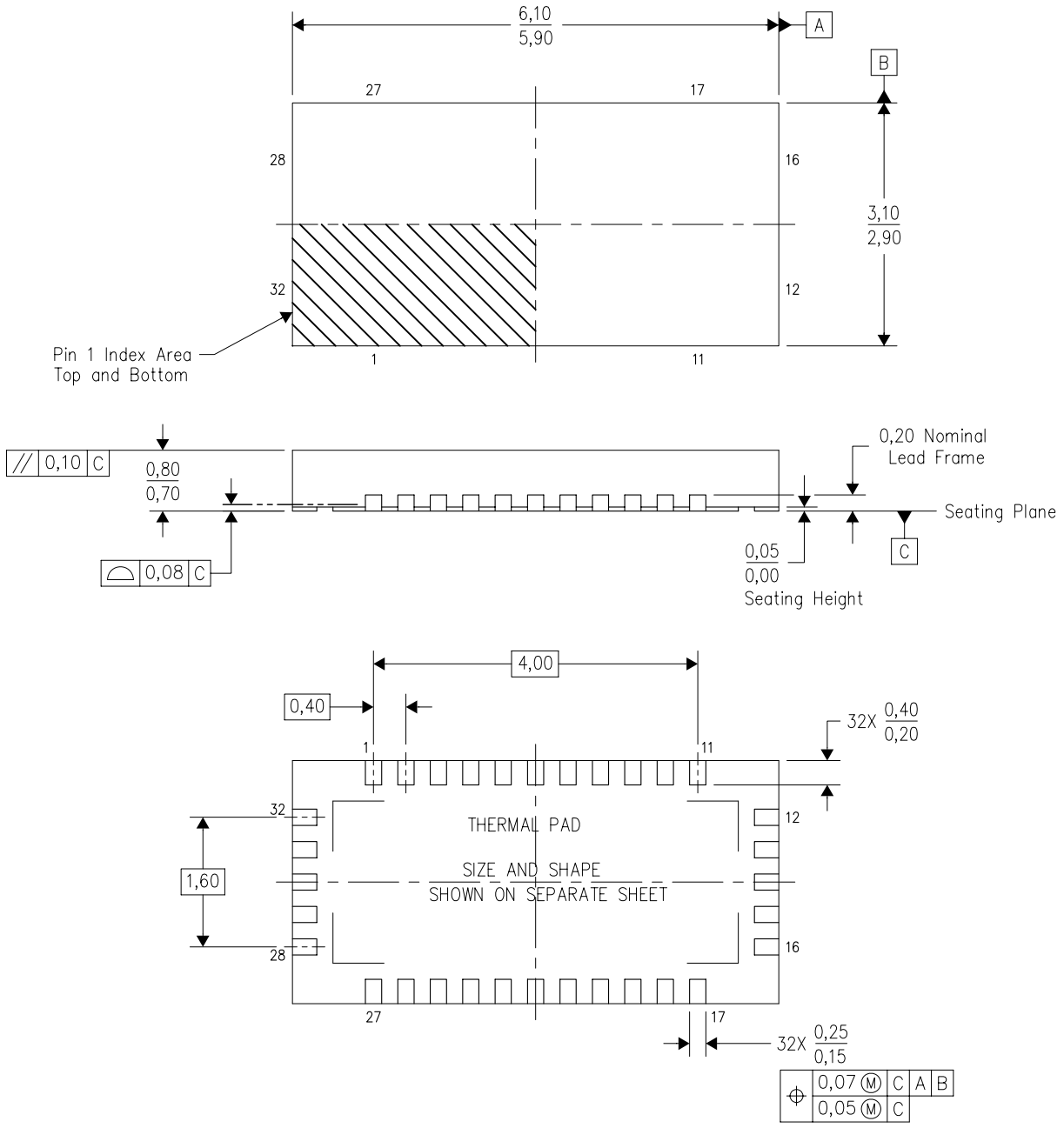
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3V713ELRTGR	WQFN	RTG	32	3000	353.0	353.0	32.0

RTG (R–PWQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Reference JEDEC MO–220.

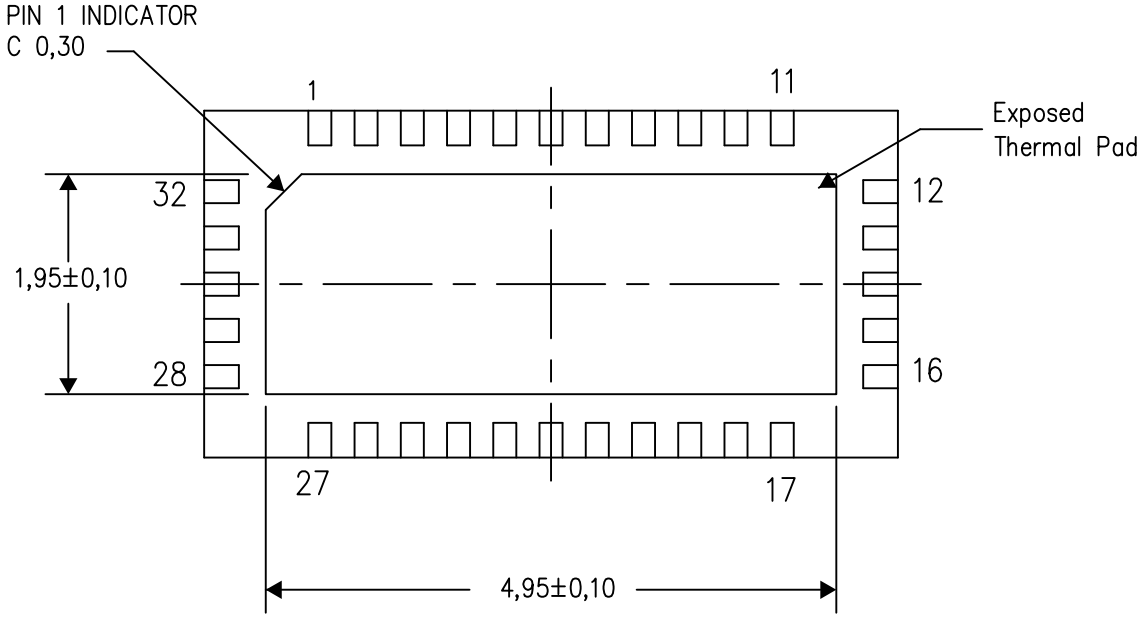
RTG (R–PWQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



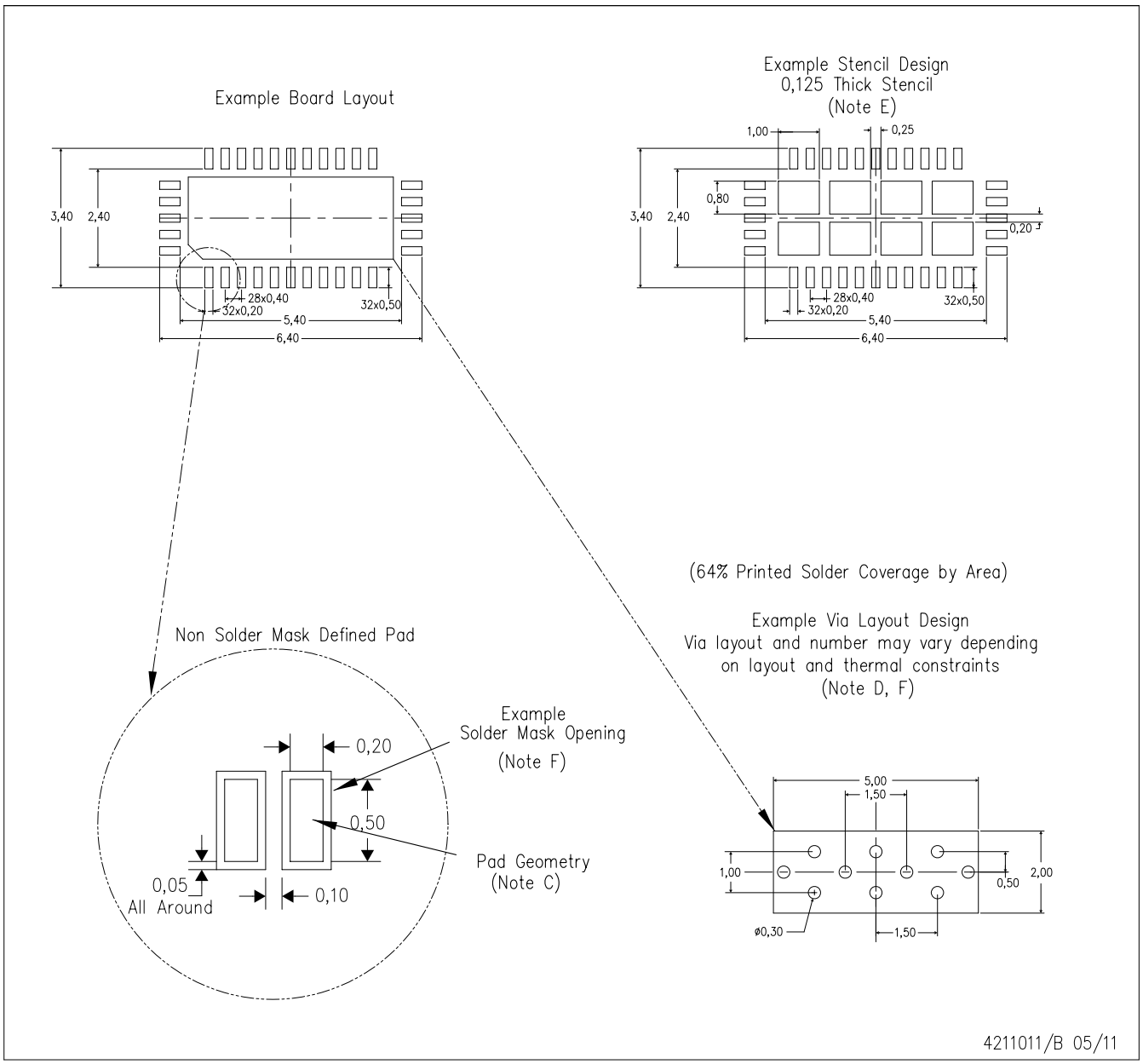
Bottom View

Exposed Thermal Pad Dimensions

4210534–2/D 12/13

NOTE: All linear dimensions are in millimeters

RTG (R–PWQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat–Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale, TI’s General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Last updated 10/2025